Vishay Semiconductors

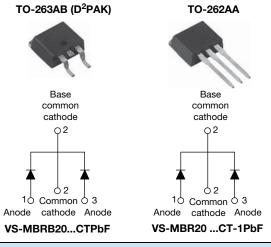
RoHS

COMPLIANT

HALOGEN

FREE

High Performance Schottky Rectifier, 2 x 10 A



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SHA

| PRODUCT SUMMARY | | | | |
|----------------------------------|---|--|--|--|
| Package | TO-263AB (D ² PAK), TO-262AA | | | |
| I _{F(AV)} | 2 x 10 A | | | |
| V _R | 80 V, 90 V, 100 V | | | |
| V _F at I _F | 0.70 V | | | |
| I _{RM} max. | 15 mA at 125 °C | | | |
| T _J max. | 150 °C | | | |
| Diode variation | Common cathode | | | |
| E _{AS} | 8.0 mJ | | | |

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Center tap D²PAK and TO-262 packages
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|-----------------------------------|--|-------------|-------|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | |
| I _{F(AV)} | Rectangular waveform (per device) | 20 | Δ | | | |
| I _{FRM} | T _C = 133 °C (per leg) | 20 | A | | | |
| V _{RRM} | | 80 to 100 | V | | | |
| I _{FSM} | t _p = 5 μs sine | 850 | А | | | |
| V _F | 10 A _{pk} , T _J = 125 °C | 0.70 | V | | | |
| TJ | Range | -65 to +150 | °C | | | |

| VOLTAGE RATINGS | | | | | | |
|--------------------------------------|------------------|---------------------------------------|---------------------------------------|---|-------|--|
| PARAMETER | SYMBOL | VS-MBRB2080CTPbF VS-MBR2080CT-1PbF | VS-MBRB2090CTPbF VS-MBR2090CT-1PbF | VS-MBRB20100CTPbF VS-MBR20100CT-1PbF | UNITS | |
| Maximum DC reverse voltage | V _R | 80 | 90 | 100 | V | |
| Maximum working peak reverse voltage | V _{RWM} | 00 | 90 | 100 | v | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|---|------------------------|---|------------|-------|--|--|
| PARAMETER | SYMBOL TEST CONDITIONS | | VALUES | UNITS | | |
| Maximum average per leg | | $T_{\rm C} = 133 ^{\circ}\text{C}$, rated $V_{\rm B}$ | 10 | | | |
| forward current per device | I _{F(AV)} | $\Gamma_{\rm C} = 105$ °C, falled $V_{\rm R}$ | 20 | 1 | | |
| Peak repetitive forward current per leg | I _{FRM} | Rated V _R , square wave, 20 kHz, T _C = 133 °C | 20 | | | |
| Non-repetitive peak surge current | | 5 μs sine or 3 μs rect. pulse Following any rated load cond and with rated V _{RRM} applied | dition 850 | А | | |
| Non-repetitive peak surge current | IFSM | Surge applied at rated load conditions half wave, single phase, 60 Hz | 150 | | | |
| Peak repetitive reverse surge current | I _{RRM} | 2.0 μs, 1.0 kHz | 0.5 | | | |
| Non-repetitive avalanche energy per leg | E _{AS} | T _J = 25 °C, I _{AS} = 2 A, L = 12 mH | 24 | mJ | | |

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| ELECTRICAL SPECIFICATIONS | | | | | | |
|--------------------------------|--------------------------------|--|--------------------------|--------|------|--|
| PARAMETER | SYMBOL | TEST C | VALUES | UNITS | | |
| | | 10 A | T ₁ = 25 °C | 0.80 | V | |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 20 A | 1j=25 0 | 0.95 | | |
| Maximum forward voltage drop | V FM (") | 10 A | T _{.1} = 125 °C | 0.70 | | |
| | | 20 A | 1j = 125 C | 0.85 | | |
| Maximum instantaneous | I _{RM} ⁽¹⁾ | T _J = 25 °C | Rated DC voltage | 0.10 | mA | |
| reverse current | IRM (") | T _J = 125 °C | haled DC vollage | 6 | | |
| Threshold voltage | V _{F(TO)} | | | 0.433 | V | |
| Forward slope resistance | r _t | $T_J = T_J maximum$ | | 15.8 | mΩ | |
| Maximum junction capacitance | CT | V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz), 25 °C | | 400 | pF | |
| Typical series inductance | L _S | Measured from top of te | 8.0 | nH | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 000 | V/µs | |

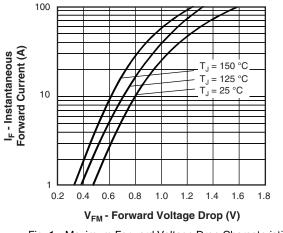
Note

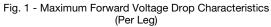
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

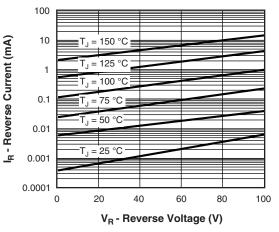
| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------------------|--------------------------------------|-------------|------------------------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Maximum junction temperature r | range T _J | | -65 to +150 | * | | |
| Maximum storage temperature ra | ange T _{Stg} | | -65 to +175 | °C | | |
| Maximum thermal resistance, junction to case per leg | R _{thJC} | DC operation | 2.0 | | | |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth and greased | 0.50 | °C/W | | |
| Maximum thermal resistance, junction to ambient | R _{thJA} | DC operation | 50 | | | |
| Approvimeto weight | | | 2 | g | | |
| Approximate weight | | | 0.07 | oz. | | |
| | imum | Non-lubricated threads | 6 (5) | kgf · cm (lbf · in) | | |
| Mounting torque max | kimum | Non-Iubricated threads | 12 (10) | | | |
| Marking davias | | Case style D ² PAK | MBRB2 | 0100CT | | |
| Marking device | | Case style TO-262 | MBR201 | 00CT-1 | | |

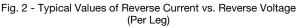


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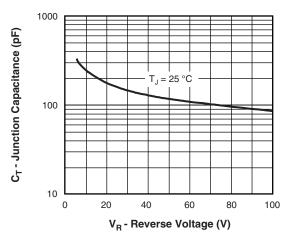
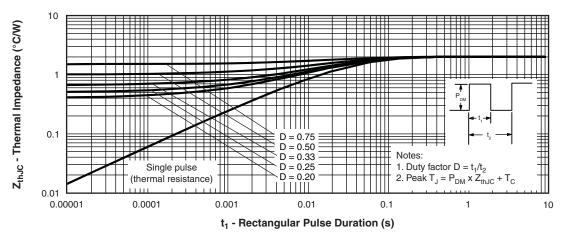
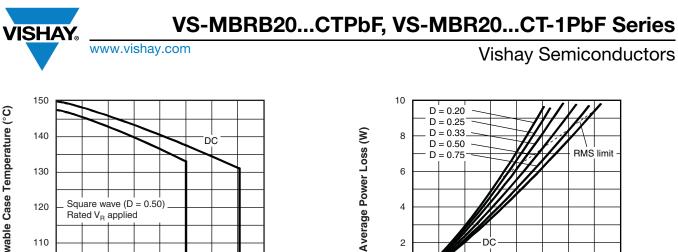


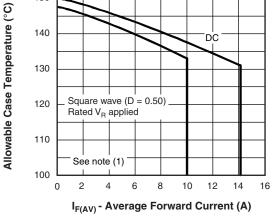
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

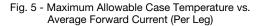




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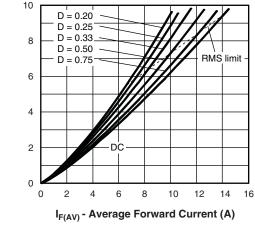


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

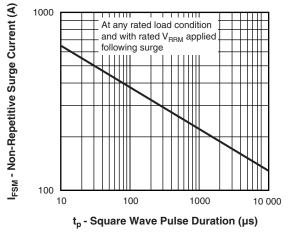


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

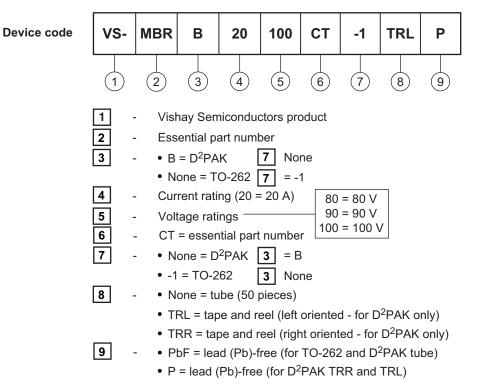
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{BEV} = inverse power loss = $V_{B1} \times I_{B} (1 - D)$; I_{B} at V_{B1} = rated V_{B1}



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ORDERING INFORMATION TABLE

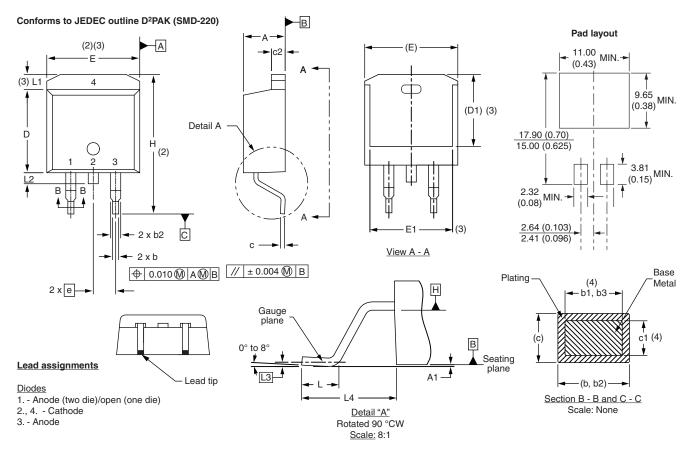


| LINKS TO RELATED DOCUMENTS | | | | |
|-------------------------------------|--------------------------|--|--|--|
| Dimensions www.vishay.com/doc?95014 | | | | |
| Part marking information | www.vishay.com/doc?95008 | | | |
| Packaging information | www.vishay.com/doc?95032 | | | |

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Vishay Semiconductors

D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

| SYMBOL | MILLIMETERS INCHES | | NOTES | | |
|---------|--------------------|-------|-------|-------|-------|
| STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.06 | 4.83 | 0.160 | 0.190 | |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| с | 0.38 | 0.74 | 0.015 | 0.029 | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 |

Notes

- $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

| SYMBOL | MILLIMETERS | | RS INCHES | | NOTES |
|----------|-------------|----------|-----------|-----------|-------|
| STIVIDUL | MIN. | MAX. | MIN. | MAX. | NULES |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 | 2.54 BSC | | 0.100 BSC | |
| Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| L | 1.78 | 2.79 | 0.070 | 0.110 | |
| L1 | - | 1.65 | - | 0.066 | 3 |
| L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| L3 | 0.25 BSC | | 0.010 | BSC | |
| L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

(7) Outline conforms to JEDEC outline TO-263AB

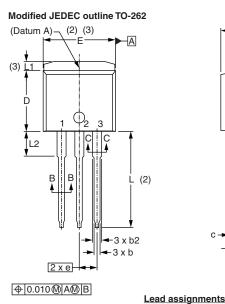
Outline Dimensions

Vishay Semiconductors

D²PAK, TO-262



DIMENSIONS - TO-262 in millimeters and inches

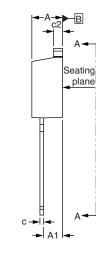


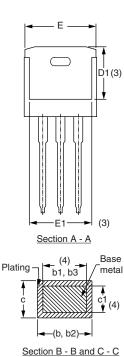
Lead tip

Diodes

3. - Anode

2., 4. - Cathode





Scale: None MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 4.06 4.83 0.160 0.190 А A1 2.03 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 0.51 0.89 0.020 0.035 4 b1 h2 1.14 1.78 0.045 0.070 b3 1.14 1.73 0.045 0.068 4 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 0.045 0.065 c2 1.65 D 8.51 9.65 0.335 0.380 2 0.270 D1 6.86 8.00 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 е 2.54 BSC 0.100 BSC L 13.46 14.10 0.530 0.555 L1 1.65 0.065 -3 L2 3.56 3.71 0.140 0.146 Notes

1. - Anode (two die)/open (one die)

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

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